

Dual N-Channel 20 V (D-S) MOSFET

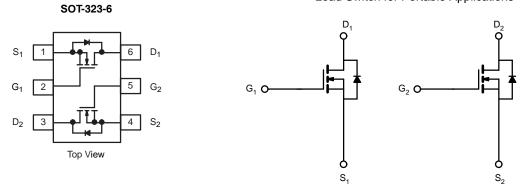
PRODUCT SUMMARY						
V _{DS} (V)	R _{DS(on)} (Ω)	I _D (A) ^a	Q _g (Typ.)			
	0.150 at V _{GS} = 4.5 V	1.8 ^a				
20	0.170 at V _{GS} = 2.5 V	1.5 ^a	0.9 nC			
	0.210 at V _{GS} = 1.8 V	1.3 ^a				

FEATURES

- Halogen-free According to IEC 61249-2-21
 Definition
- TrenchFET[®] Power MOSFET
- 100 % R_g Tested
- Typical ESD Protection 2100 V HBM
- Compliant to RoHS Directive 2002/95/EC

APPLICATIONS

· Load Switch for Portable Applications



Parameter	Symbol	Limit	Unit	
Drain-Source Voltage	V _{DS}	20	V	
Gate-Source Voltage		V _{GS}	± 8	V
	T _C = 25 °C		1.8 ^a	
Continuous Prois Current $(T_{-} = 150 ^{\circ}\text{C})$	T _C = 70 °C		1.5 ^a	
Continuous Drain Current ($T_J = 150 \ ^{\circ}C$)	T _A = 25 °C	I _D	1.3 ^{a, b, c}	
	T _A = 70 °C		1.2 ^{b, c}	А
Pulsed Drain Current	I _{DM}	4		
Continuous Source-Drain Diode Current	T _C = 25 °C		1	
Continuous Source-Drain Diode Current	T _A = 25 °C	I _S	0.61 ^{b, c}	
	T _C = 25 °C		1.25	
Maximum Dawar Dissipation	T _C = 70 °C		0.8	w
Maximum Power Dissipation	T _A = 25 °C	P _D	0.74 ^{b, c}	VV
	T _A = 70 °C		0.47 ^{b, c}	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150	°C

THERMAL RESISTANCE RATINGS							
Parameter		Symbol	Typical	Maximum	Unit		
Maximum Junction-to-Ambient ^{b, d}	t ≤ 5 s	R _{thJA}	130	170	°C/W		
Maximum Junction-to-Foot (Drain)	Steady State	R _{thJF}	80	100			

Notes:

a. Package limited.b. Surface mounted on 1" x 1" FR4 board.

c. t = 5 s.

d. Maximum under steady state conditions is 220 °C/W.



RoHS COMPLIANT HALOGEN FREE

DTS2212

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Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static							
ain-Source Breakdown Voltage V _{DS}		$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$	20			V	
V _{DS} Temperature Coefficient	$\Delta V_{DS}/T_{J}$	L 050		20		mV/°C	
V _{GS(th)} Temperature Coefficient	$\Delta V_{GS(th)}/T_J$	I _D = 250 μΑ		- 2.3			
Gate-Source Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = 250 \ \mu A$	0.4		1	V	
	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 8 V$			± 25	μA	
Gate-Source Leakage		$V_{DS} = 0 \text{ V}, V_{GS} = \pm 4.5 \text{ V}$			1		
Zara Cata Valtaga Drain Current		$V_{DS} = 20 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$			1	μA	
Zero Gate Voltage Drain Current	IDSS	$V_{DS} = 20 \text{ V}, \text{ V}_{GS} = 0 \text{ V}, \text{ T}_{J} = 55 \text{ °C}$			10		
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \le 5 \text{ V}, V_{GS} = 4.5 \text{ V}$	4			Α	
		V _{GS} = 4.5 V, I _D = 1 A	0.150 0.19		0.198		
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = 2.5 V, I _D = 1 A		0.170	0.225	Ω	
		V _{GS} = 1.8 V, I _D = 0.2 A		0.210	0.263		
Forward Transconductance ^a	9 _{fs}	V _{DS} = 4 V, I _D = 1.5 A		4		S	
Dynamic ^b				•	•		
Tatal Oata Ohanna	Qg	$V_{DS} = 10 \text{ V}, \text{ V}_{GS} = 8 \text{ V}, \text{ I}_{D} = 1.5 \text{ A}$		1.6	2.5	nC	
Total Gate Charge				0.9	1.8		
Gate-Source Charge	Q _{gs}	V_{DS} = 10 V, V_{GS} = 4.5 V, I_{D} = 1.5 A		0.1			
Gate-Drain Charge	Q _{gd}			0.2			
Gate Resistance	R _g	f = 1 MHz	0.4	1.9	3.8	kΩ	
Turn-On Delay Time	t _{d(on)}			43	65	- ns	
Rise Time	t _r	V_{DD} = 10 V, R_{L} = 8.3 Ω		80	120		
Turn-Off Delay Time	t _{d(off)}	$I_D \cong 1.2$ Å, $V_{GEN} = 4.5$ V, $R_g = 1 \Omega$		480	720		
Fall Time	t _f			220	330		
Turn-on Delay Time	t _{d(on)}			22	33		
Rise Time	tr	V_{DD} = 10 V, R_L = 8.3 Ω		46	70		
Turn-Off Delay Time	t _{d(off)}	${\rm I_D}\cong {\rm 1.2~A,~V_{GEN}=8~V,~R_g=1~\Omega}$		645	968		
Fall Time	tr			215	323		
Drain-Source Body Diode Characteristic	s						
Continuous Source-Drain Diode Current	ا _S	T _C = 25 °C			1	^	
Pulse Diode Forward Current	I _{SM}				4	A	
Body Diode Voltage	V _{SD}	$I_{S} = 1.2 \text{ A}, V_{GS} = 0 \text{ V}$		0.8	1.2	V	
Body Diode Reverse Recovery Time	t _{rr}			9	18	ns	
Body Diode Reverse Recovery Charge	Q _{rr}			2	4	nC	
Reverse Recovery Fall Time	t _a	I _F = 1.2 A, dl/dt = 100 A/µs, T _J = 25 °C		5			
Reverse Recovery Rise Time	t _b			4		ns	

Notes:

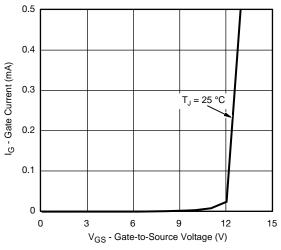
a. Pulse test; pulse width \leq 300 $\mu s,$ duty cycle \leq 2 %.

b. Guaranteed by design, not subject to production testing.

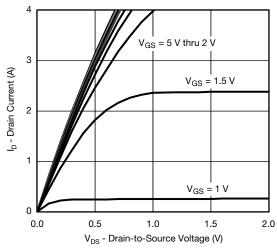
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



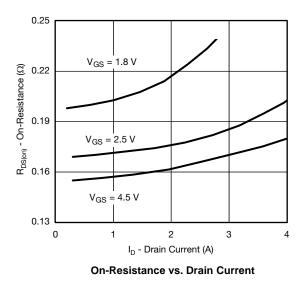
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Gate Current vs. Gate-to-Source Voltage



Output Characteristics



10⁻³ 10-4 10-5 T_J = 150 °C I_G - Gate Current (A) 10-6 10-7 = 25 °C ТJ 10-8 10⁻⁹ 10-10 0 3 6 9 12 15 V_{GS} - Gate-to-Source Voltage (V) Gate Current vs. Gate-to-Source Voltage 1.0 0.8 I_D - Drain Current (A) 0.6 T_C = 25 °C 0.4 T_C = 125 °C 0.2 T_C = - 55 °C 0.0



V_{GS} - Gate-to-Source Voltage (V)

0.9

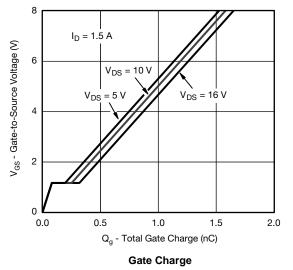
1.2

1.5

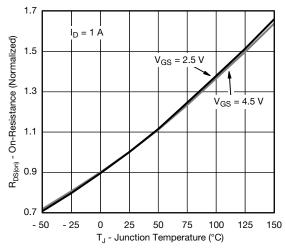
0.6

0.0

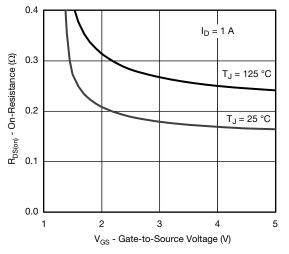
0.3



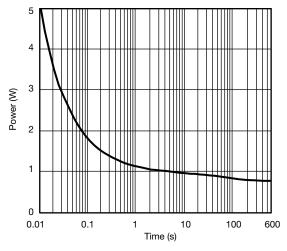
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



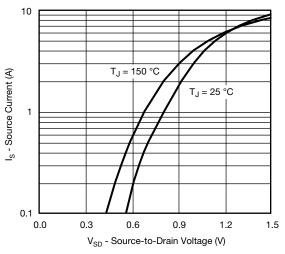
On-Resistance vs. Junction Temperature



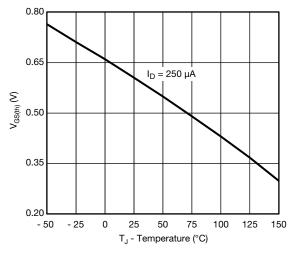
On-Resistance vs. Gate-to-Source Voltage



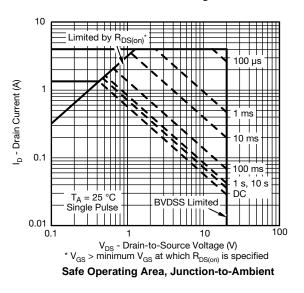
Single Pulse Power, Junction-to-Ambient



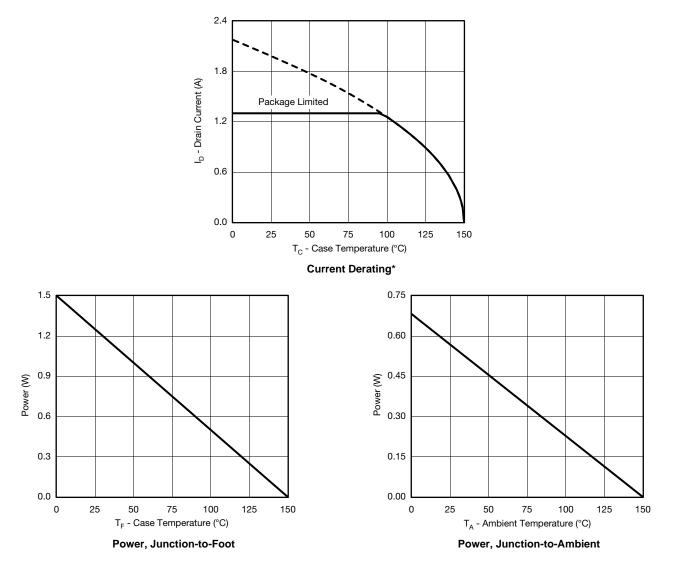
Source-Drain Diode Forward Voltage



Threshold Voltage

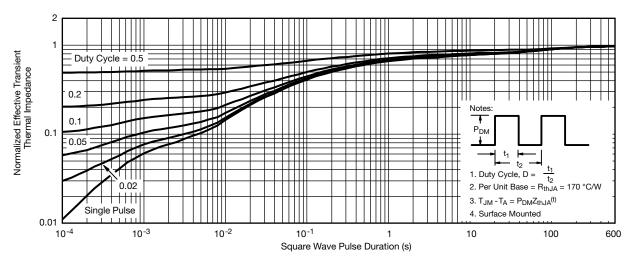


TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

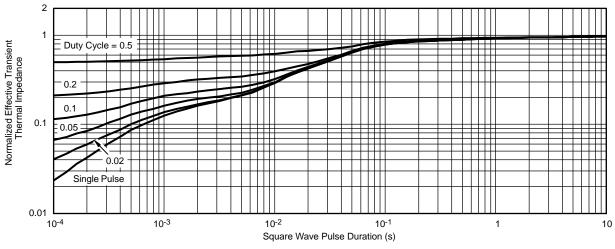


* The power dissipation P_D is based on $T_{J(max)} = 150 \text{ °C}$, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit.

TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



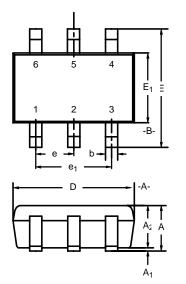
Normalized Thermal Transient Impedance, Junction-to-Ambient

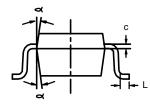


Normalized Thermal Transient Impedance, Junction-to-Foot



Package Information www.din-tek.jp

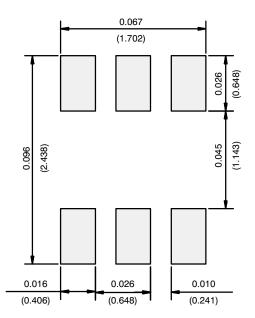




	MILLIMETERS			INCHES			
Dim	Min	Nom	Max	Min	Nom	Max	
Α	0.90	-	1.10	0.035	-	0.043	
A ₁	-	-	0.10	-	-	0.004	
A ₂	0.80	-	1.00	0.031	-	0.039	
b	0.15	-	0.30	0.006	-	0.012	
С	0.10	-	0.25	0.004	-	0.010	
D	1.80	2.00	2.20	0.071	0.079	0.087	
Е	1.80	2.10	2.40	0.071	0.083	0.094	
E ₁	1.15	1.25	1.35	0.045	0.049	0.053	
е	0.65BSC			0.026BSC			
e ₁	1.20	1.30	1.40	0.047	0.051	0.055	
L	0.10	0.20	0.30	0.004	0.008	0.012	
٩	7°Nom			7°Nom			



RECOMMENDED MINIMUM PADS FOR SOT323: 6-Lead



Recommended Minimum Pads Dimensions in Inches/(mm)



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